



Product Summarv

| BV _{DSS} | R _{DS(ON)} MAX | Package | Ι _{D MAX} Τ _A = +25°C |
|-------------------|---------------------------------|---------|--|
| -20V | 110mΩ @ V _{GS} = -4.5V | SOT23 | -2.6A |
| -200 | $225m\Omega @ V_{GS} = -2.5V$ | | -2.0A |

Description

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- General Purpose Interfacing Switch
- **Power Management Functions**

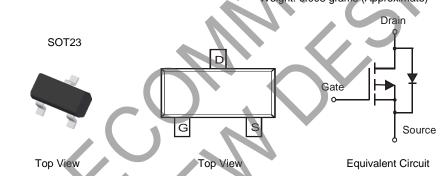
P-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (DMP2225LQ)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 3
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)



Ordering Information (Note 4)

| Part Number | Qualification | Case | Packaging |
|-------------|---------------|-------|------------------|
| DMP2225L-7 | Standard | SOT23 | 3000/Tape & Reel |

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes:

2. See http://www.diodes.com/quality/lead_free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds. 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

| 2P2 | ΜY |
|-----|----|
| | |

2P2 = Product Type Marking Code YM or $\overline{Y}M$ = Date Code Marking Y or \overline{Y} = Year (ex: G = 2019) M = Month (ex: 9 = September)

Date Code Key

| Year | 2008 | | 2009 | ~ | | 2017 | 2018 | | 2019 | 2020 |) | 2021 |
|-------|------|-----|------|-----|-----|------|------|-----|------|------|-----|------|
| Code | V | | W | ~ | | E | F | | G | Н | | |
| Month | Jan | Feb | Mar | Apr | Мау | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |



DMP2225L

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteri | stic | | Symbol | Value | Unit |
|-----------------------------------|--|------------------|------------------|------------|------|
| Drain-Source Voltage | | | V _{DSS} | -20 | V |
| Gate-Source Voltage | | V _{GSS} | ±12 | V | |
| Continuous Drain Current (Note 5) | Steady $T_A = +25^{\circ}C$ State $T_A = +70^{\circ}C$ | | ID | -2.6 -2 | А |
| Pulsed Drain Current (Note 6) | | I _{DM} | -8 | A | |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|--|------------------|-------------|------|
| Total Power Dissipation (Note 5) | PD | 1.08 | W |
| Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 5) | R _{θJA} | 115 | °C/W |
| Operating and Storage Temperature Range | TJ, TSTG | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

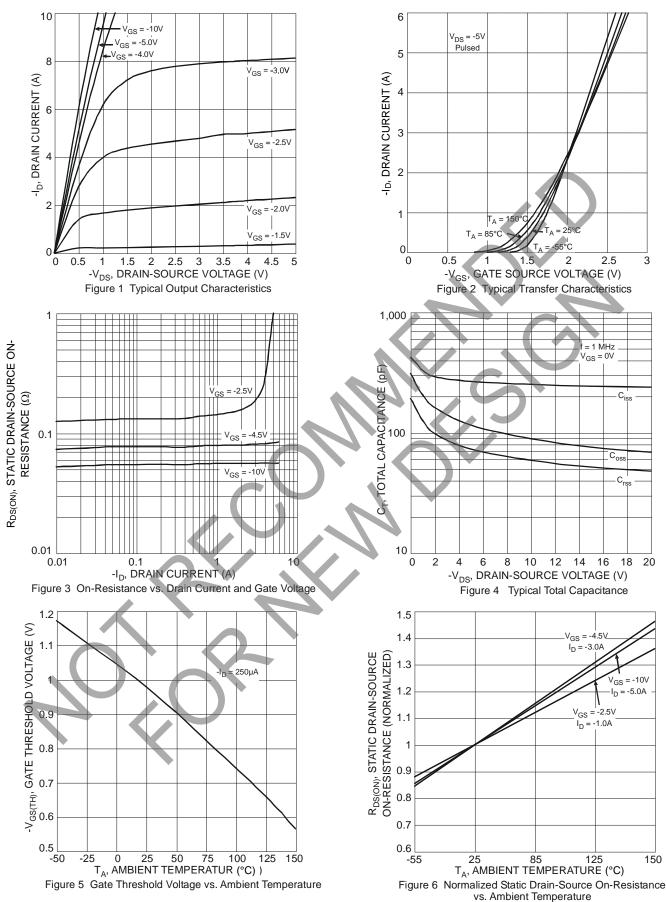
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|-------------------------------------|---------------------|----------|-----|-------|------|--|
| OFF CHARACTERISTICS (Note 7) | | | | | | |
| Drain-Source Breakdown Voltage | BVDSS | -20 | — | | V | $V_{GS} = 0V, I_D = -250 \mu A$ |
| Zero Gate Voltage Drain Current | I _{DSS} | — | • _ | -800 | nA | $V_{DS} = -20V, V_{GS} = 0V$ |
| On-State Drain Current | ID(ON) | -6 -3 | | | А | $V_{DS} \le -5V, V_{GS} = -4.5V$ $V_{DS} \le -5V, V_{GS} = -2.5V$ |
| Gate-Source Leakage | IGSS | | | ±80 | nA | $V_{GS} = \pm 12V, V_{DS} = 0V$ |
| ON CHARACTERISTICS (Note 7) | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | -0.45 | — | -1.25 | V | $V_{DS} = V_{GS}, I_{D} = -250 \mu A$ |
| Static Drain-Source On-Resistance | | | 80 | 110 | mΩ | $V_{GS} = -4.5V, I_D = -2.6A$ |
| Static Dialit-Source Off-Resistance | RDS(ON) | | 165 | 225 | | $V_{GS} = -2.5V, I_D = -2.0A$ |
| Forward Transfer Admittance | Y _{fs} | _ | 4 | _ | s | $V_{DS} = -5V, I_D = -2.6A$ |
| Diode Forward Voltage (Note 6) | V _{SD} | _ | _ | -1.26 | V | $V_{GS} = 0V, I_{S} = -2.6A$ |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | |
| Input Capacitance | Ciss | | 250 | _ | pF | |
| Output Capacitance | Coss | — | 88 | _ | рF | V _{DS} = -10V, V _{GS} = 0V f = 1.0MHz |
| Reverse Transfer Capacitance | Crss | — | 58 | — | pF | 1 = 1.0MH2 |
| Gate Resistance | Rg | — | 12 | 16 | Ω | $V_{GS} = 0V, V_{DS} = 0V, f = 1MHz$ |
| Total Gate Charge | Qg | — | 4.3 | 5.3 | | |
| Gate-Source Charge | Qgs | — | 0.9 | — | nC | $V_{GS} = -4.5V, V_{DS} = -10V,$ |
| Gate-Drain Charge | Q _{gd} | _ | 2.1 | — | | I _D = -2.7A |

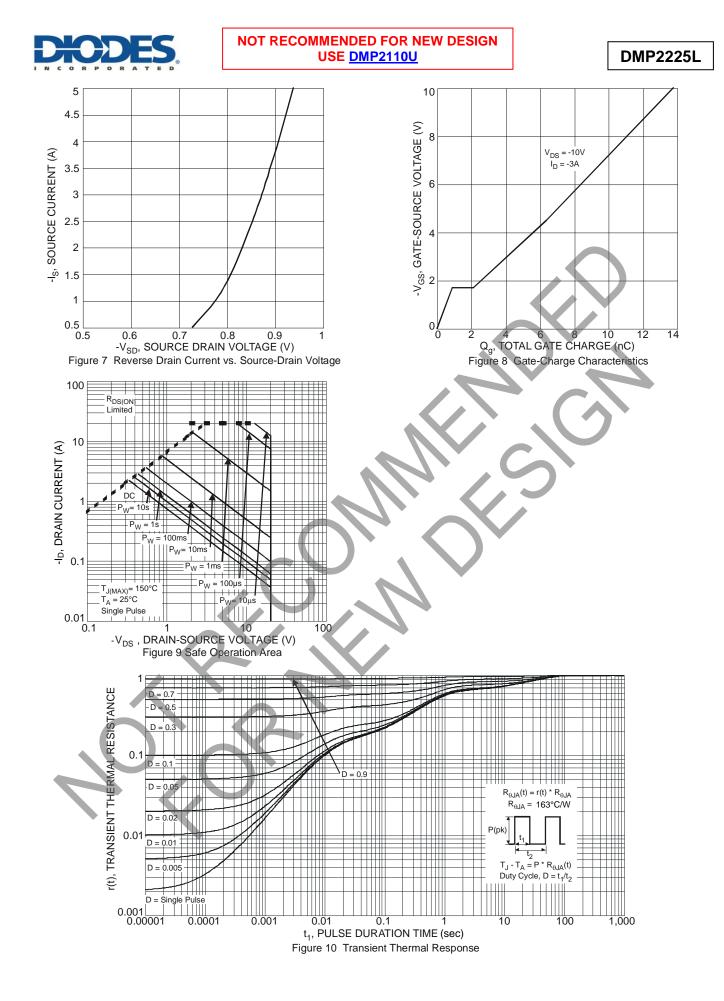
 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
6. Repetitive rating, pulse width limited by junction temperature.
7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to production testing. Notes:



NOT RECOMMENDED FOR NEW DESIGN USE <u>DMP2110U</u>

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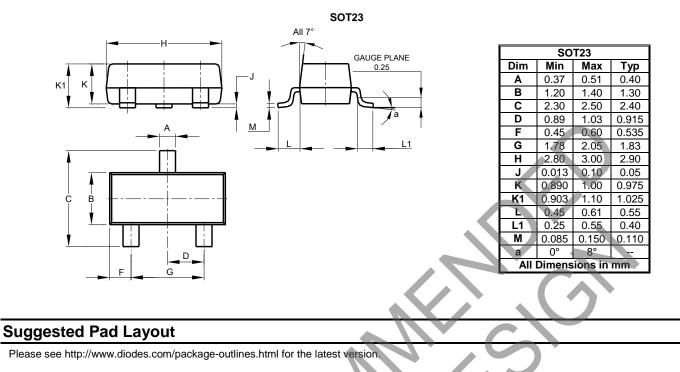


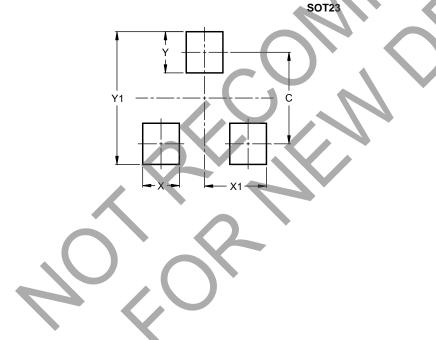




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.





| Dimensions | Value (in mm) |
|------------|---------------|
| С | 2.0 |
| Х | 0.8 |
| X1 | 1.35 |
| Y | 0.9 |
| Y1 | 2.9 |



DMP2225L

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